# MSKSEMI















**ESD** 

**TVS** 

**TSS** 

MOV

**GDT** 

**PLED** 

Broduct data speet



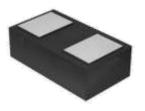




#### **Features**

Ultra Low Capacitance: 0.30pF(typ.) Reverse Working Voltage: 5V IEC 61000-4-2 (ESD Air): ±20kV IEC 61000-4-2 (ESD Contact): ±20kV IEC 61000-4-5 (Lightning 8/20µs): 5A

## **Pin Description**



# **Applications**

Smart Phone and Tablet PC TV and Set Top Box Wearable Devices PDA

### **Schematic Diagram**



# Limiting Values( $T_A = 25$ °C, unless otherwise specified)

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>ESD</sub> Electrostatic Discharge Voltage	Clastrostatic Discharge Voltage	IEC 61000-4-2; Contact Discharge	-	±20	kV
	IEC 61000-4-2; Air Discharge	-	±20	kV	
P <sub>PP</sub>	Peak Pulse Power	t <sub>P</sub> = 8/20 μs	-	110	W
ІРРМ	Rated Peak Pulse Current	t <sub>P</sub> = 8/20 μs	ı	5.0	Α
T <sub>A</sub>	Operating Temperature Range	-	-55	125	$^{\circ}$
T <sub>stg</sub>	Storage Temperature Range	-	-55	150	$^{\circ}\!\mathbb{C}$







Symbol	Parameter	Conditions	Min	Тур.	Max	Unit
V <sub>RWM</sub>	Reverse Working Voltage	T <sub>A</sub> = 25 °C	-	-	5.0	V
$V_{BR}$	Breakdown Voltage	I <sub>R</sub> = 1mA; T <sub>A</sub> = 25 °C	6.0	8.5	9.5	V
I <sub>R</sub>	Reverse Leakage Current	V <sub>RWM</sub> = 5V; T <sub>A</sub> = 25 °C	-	-	0.1	μA
Vc	Clamping Voltage	I <sub>PP</sub> =1A, t <sub>P</sub> =8/20μs	-	-	10	V
		I <sub>PP</sub> =5.0A, t <sub>P</sub> =8/20μs	-	-	22	V
Сл	Junction Capacitance	V <sub>R</sub> = 0V, f = 1 MHz	-	0.30	0.40	pF

## **Typical Characteristics**

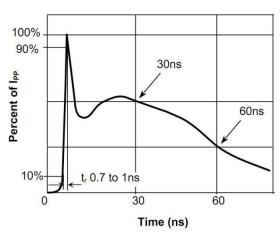


Fig.1 Pulse Waveform-ESD (IEC61000-4-2)

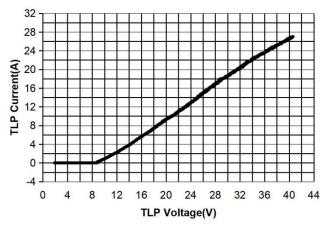


Fig.2 Transmission Line Pulse (TLP)

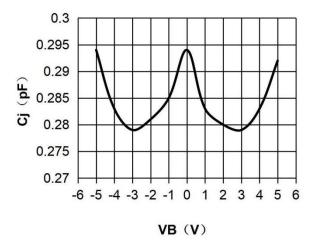


Fig.3 Capacitance vs. Reveres Voltage

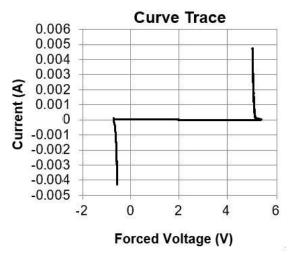
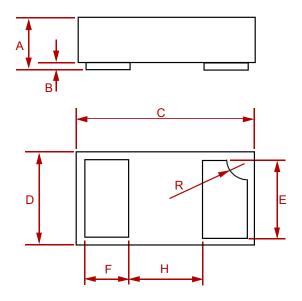


Fig.4 IV Curve

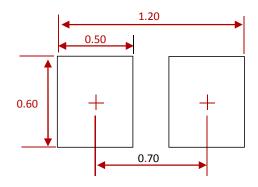


#### **PACKAGE MECHANICAL DATA**



Dim	Inches		Millimeters		
Dim	MIN	MAX	MIN	MAX	
Α	0.0125	0.02	0.32	0.52	
В	0.000	0.002	0.00	0.05	
С	0.037	0.043	0.95	1.080	
D	0.022	0.027	0.55	0.680	
Е	0.016	0.024	0.40	0.60	
F	0.008	0.012	0.20	0.30	
Н	0.015Typ.		0.40Typ.		
R	0.001	0.005	0.05	0.15	

# **Suggested Pad Layout**



#### NOTES:

- 1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
- 2. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY. CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR COMPANY'S MANUFACTURING GUIDELINES ARE MET.

#### **REEL SPECIFICATION**

P/N	PKG	QTY
LXES1UTAA1-MS	DFN-2	10000



Semiconductor



## **Attention**

- Any and all MSKSEMI Semiconductor products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your MSKSEMI Semiconductor representative nearest you before using any MSKSEMI Semiconductor products described or contained herein in such applications.
- MSKSEMI Semiconductor assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all MSKSEMI Semiconductor products described or contained herein.
- Specifications of any and all MSKSEMI Semiconductor products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- MSKSEMI Semiconductor. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with someprobability. It is possiblethat these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits anderror prevention circuitsfor safedesign, redundant design, and structural design.
- In the event that any or all MSKSEMI Semiconductor products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from theauthorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of MSKSEMI Semiconductor.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. MSKSEMI Semiconductor believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. Whendesigning equipment, referto the "Delivery Specification" for the MSKSEMI Semiconductor productthat you intend to use.